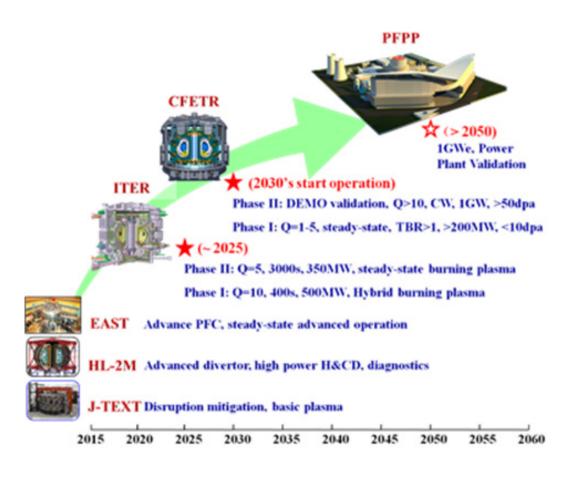# Ansys 15 Magnitude Crack Cs3

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 Best of luck for a great weekend. Cheers, james Paul wrote:Best of luck for a great weekend. Cheers, jamesMany types of memory devices are known in the art. Some memory devices are based on a bi-stable flip-flop circuit, which stores digital bits. Another class of memory devices uses transistors or diodes as a memory device. Generally, these latter devices are volatile, in that they lose their stored bits when power is removed or turned off. Electrically programmable and erasable non-volatile memory devices (i.e., memory devices which retain stored bits after having power removed or turned off) are presently in widespread use in a number of applications. A currently popular form of such a non-volatile memory device includes an array of floating-gate memory cells. Each memory cell can be electrically programmed or

erased by altering the charge on a floating gate. FIG. 1 illustrates a portion of an example of a conventional non-volatile memory device, having an array of floating gate memory cells, such as that disclosed in U.S. Pat. No. 5,066,608, entitled "Nonvolatile Semiconductor Memory Device Having A Storage Diode That Can Store More Than One Bit Of Information," issued to Reichert et al. on Oct. 19, 1991, the disclosure of which is incorporated herein by reference. This figure illustrates one of many implementations of a floating gate memory cell. The memory cell includes a source region 16, a drain region 18 and a channel region 20 in a substrate 22. A floating gate 24 is provided above a portion of the channel region 20, while a control gate 26 is provided above the floating gate 24. The control gate 26 is also electrically coupled to a word line 28 which is generally used to control the access of the memory cell. The control gate of each memory cell is electrically coupled to a control gate line 30, and a word line of the memory cell is electrically coupled to a word line line 32. The control gate line is used to apply a voltage to the control gate of a cell in order to program or erase the cell. A pair of bit lines 36 and 38 are also provided in the array. The bit 82157476af

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